TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT (Under 37 CFR 1.97(b) or 1.97(c))				Docket No. LEE.002				
In Re Application Of: Shone FUJA								
Serial No.			Filing Date	Examiner		Group Art Unit		
		NEW	JANUARY 5, 2004	TO BE ASSIGNED		TO BE ASSIGNED		
Ti	tle:	NON-VOLATILE	MEMORY ARRAY HAVING V	ERTICAL TRANSISTORS A	ND MA	ANUFACTURING		
METHOD THEREOF								
	Address to:  Commissioner for Patents  P.O. Box 1450  Alexandria, VA 22313-1450							
			37 C	FR 1.97(b)	-			
1.	×	The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.						
			37 C	FR 1.97(c)				
2.		The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:						
		☐ the staten	nent specified in 37 CFR 1.97(e);	;				
			OR					
		☐ the fee se	et forth in 37 CFR 1.17(p).					

	OSURE STATEMENT 7(c))	Docket No. LEE.002					
In Re Application: Shone FUJA							
Serial No.	Filing Date	Examiner	Group Art Unit				
NEW	JANUARY 5, 2004	TO BE ASSIGNED	TO BE ASSIGNED				
NON-VOLATILE MEMORY ARRAY HAVING VERTICAL TRANSISTORS AND METHOD THEREOF							
	Payı	ment of Fee					
	(Only complete if Applicant el	ects to pay the fee set forth in 37 CFR 1.1	7(p))				
as described belo Charge th Credit any Charge a Certificate of T	ne amount of y overpayment. ny additional fee required.  Fransmission by Facsimile*  ent and authorization to charge deposit mile transmitted to the United States	Certificate of Mailing by First Class Mail  I certify that this document and fee is being deposited on with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.					
	Signature	Signature of Person Mails	son Mailing Correspondence				
Typed or Printed N	lame of Person Signing Certificate	Typed or Printed Name of Person	n Mailing Certificate				
*This certificate may only be used if paying by deposit account.  Dated: JANUARY 5, 2004  ADAM C. VOLENTINE REG. NO. 33,289  VOLENTINE FRANCOS, P.L.L.C. 12200 SUNRISE VALLEY DRIVE, SUITE 150 RESTON, VA 20191  TEL. NO.: (703) 715-0870							

## INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)	Application Number		
LEE.002	NEW		
Applicant(s)			

Shone FUJA

Filing Date

January 5, 2004

Group Art Unit To Be Assigned

				U.S. PATENT DOCUMENTS				
*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING IF APPRO	DATE OPRIATE
	A	5,739,567	04/14/1998	WONG				
	В	5,770,514	06/23/1998	MATSUDA et al.				
	С	6,544,824	04/08/2003	PRADEEP et al.				
	D	6,365,452	04/02/2002	PERNG et al.				
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	•			FOREIGN PATENT DOCUMENTS	<u> </u>	·•		
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Trans	slation
		<u> </u>					YES	NO
		<u> </u>						<u> </u>
						-		
				OTHER DOCUMENTS (Including				
	R. Muralidhar et al., "A 6V Embedded 90nm Silicon Nanocrystal Nonvolatile Memory", DigitalDNA Laboratories and the embedded Memory Center, 2003 IEEE, 4 pgs.						and the	
		E						
	B. De Salvo et al.,"How far will Silicon nanocrystals push the scaling limits of NVMs technologies?", 2003 IEEE, 4 pgs.					pgs.		
		F						
EXAMINE	R			DATE CONSIDERED			4	

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Form PTO-A820 (also form PTO-1449) P09A/REV04

Patent and Trademark Office \* U.S. DEPARTMENT OF COMMERCE

SHEET 1

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